Appln. No.: Applied for Docket No.: SNDK.294US0
Title: Bitline Direction Shielding To Avoid Cross Coupling Between Adjacent Cells for Nand Flash Memory
Inventors: G. Matamis et al. Exp. Mail: EV 321715981
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 1 of 5

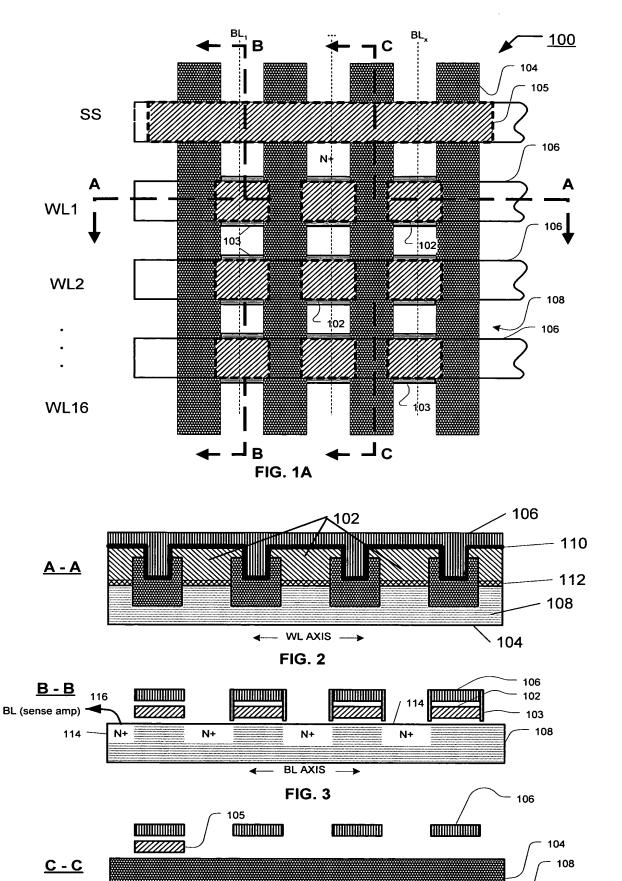


FIG. 4

Appln. No.: Applied for Docket No.: SNDK.294US0
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Inventors: G. Matamis et al. Exp. Mail: EV 321715981 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 2 of 5

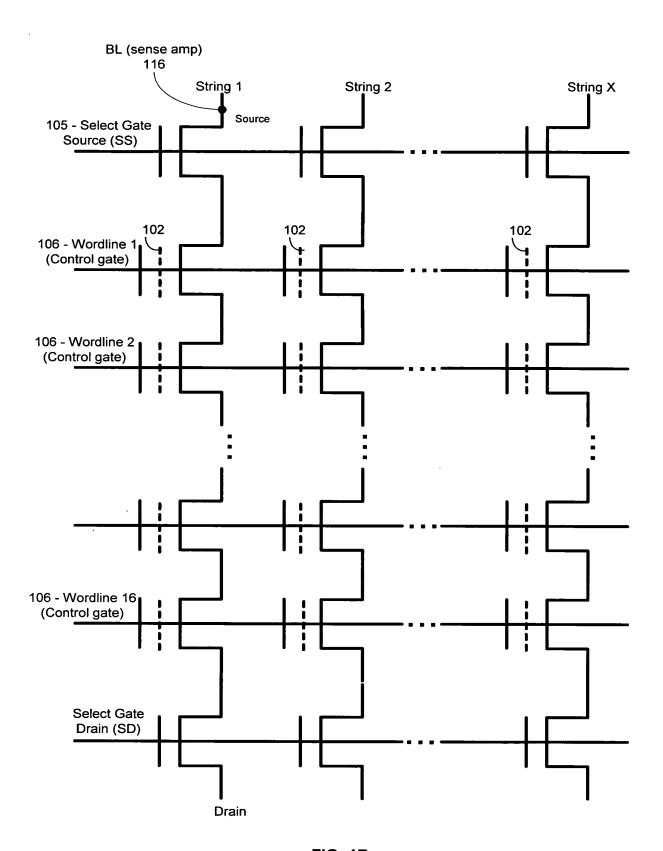
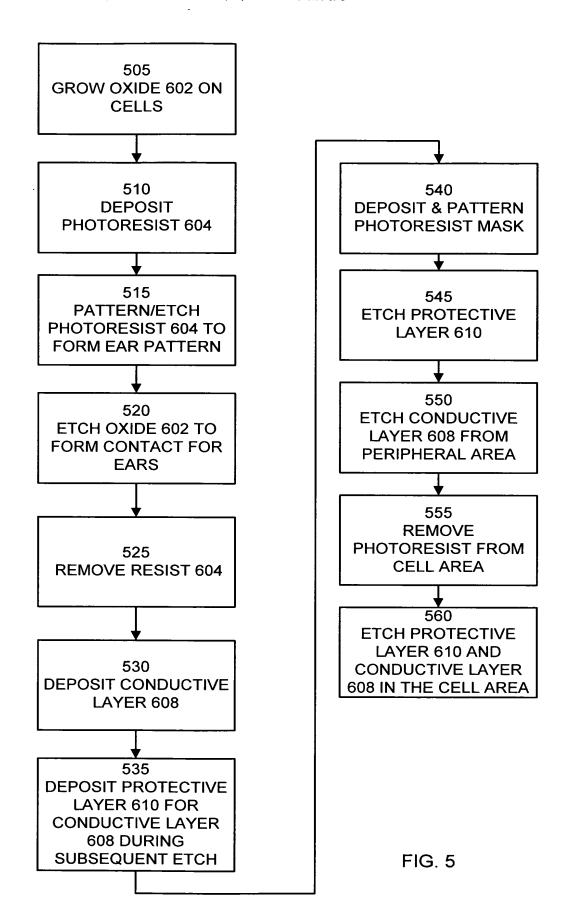


FIG. 1B

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Inventors: G. Matamis et al. Exp. Mail: EV 321715981 US
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Appln. No.: Applied for Docket No.: SNDK.294USO
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Inventors: G. Matamis et al. Exp. Mail: EV 321715981 US
Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 4 of 5

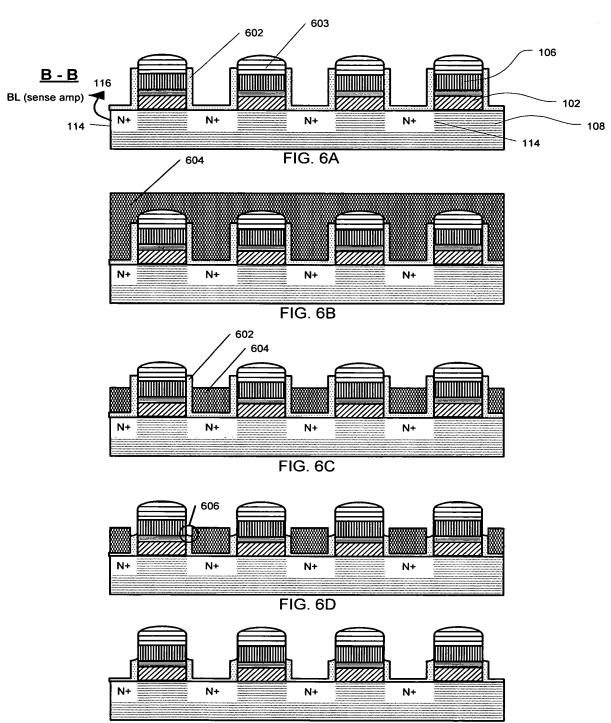


FIG. 6E

Appln. No.: Applied for Docket No.: SNDK.294USO

Title: Bitline Direction Shielding To Avoid Cross Coupling Between Adjacent Cells for Nand Flash Memory
Inventors: G. Matamis et al. Exp. Maif: EV 321715981 US 1 of 5

Filing Date: Herewith Atty. Tel: (415) 318-1160 Sheet 5 of 5

608 N+ N+ N+ N+

FIG. 6F

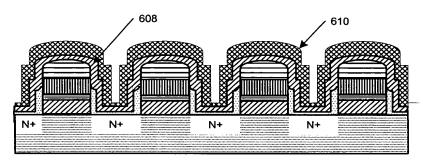


FIG. 6G

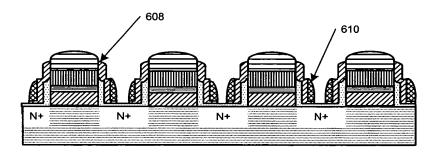


FIG. 6H